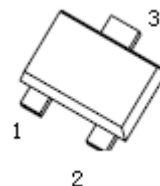


N- Channel MOSFET

SOT-723

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
30V	$8\Omega @4V$	100mA
	$13\Omega @2.5V$	



1. GATE
2. SOURCE
3. DRAIN

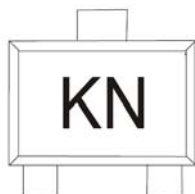
FEATURES

- Low on-resistance
- Fast switching speed
- Low voltage drive makes this device ideal for Portable equipment
- Drive circuits can be simple
- Parallel use is easy

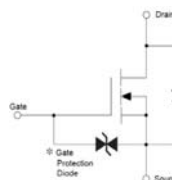
APPLICATION

- Interfacing , Switching

MARKING



Equivalent Circuit



Maximum ratings ($T_a=25^\circ\text{C}$ unless other wise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	30	V
Gate-source voltage	V_{GS}	± 20	
Continuous drain current	I_D	± 100	mA
Power dissipation	P_D	0.15	W
Thermal resistance from junction to ambient	$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$
Junction temperature	T_J	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 ~+150	

* $P_w \leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

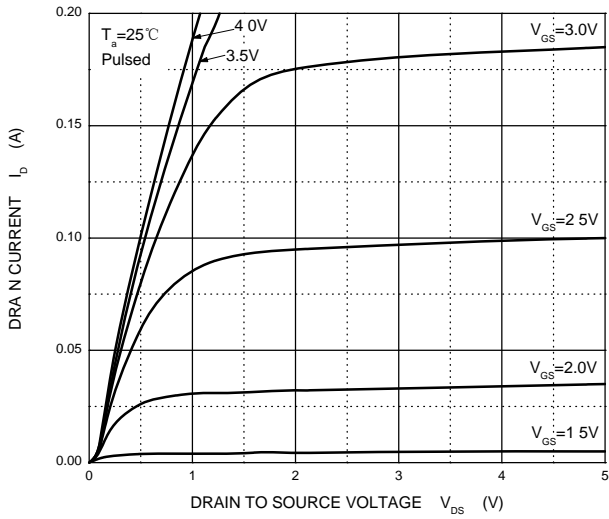
**MOSFET ELECTRICAL CHARACTERISTICS****T_a=25°C unless otherwise specified**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 10μA	30			V
Gate-source leakage current	I _{GSS}	V _{DS} = 0V, V _{GS} = ±20V			±2	μA
Zero gate voltage drain current	I _{DSS}	V _{DS} = 30V, V _{GS} = 0V			1.0	μA
Gate threshold voltage	V _{GS(th)}	V _{DS} = 3V, I _D = 100μA	0.8		1.5	V
Static drain-source on-state resistance	R _{DS(on)}	V _{GS} = 4V, I _D = 10mA		5	8	Ω
		V _{GS} = 2.5V, I _D = 1mA		7	13	
Forward transconductance	g _{FS}	V _{DS} = 3V, I _D = 10mA	20			mS
Input capacitance	C _{iss}	V _{DS} = 5V, V _{GS} = 0V, f = 1MHz		13		pF
Output capacitance	C _{oss}			9		
Reverse transfer capacitance	C _{rss}			4		
Turn-on delay time	t _{d(on)}	V _{GS} = 5V, V _{DD} = 5V, I _D = 10mA R _L = 500Ω, R _G = 10Ω		15		ns
Rise time	t _r			35		
Turn-off delay time	t _{d(off)}			80		
Fall time	t _f			80		

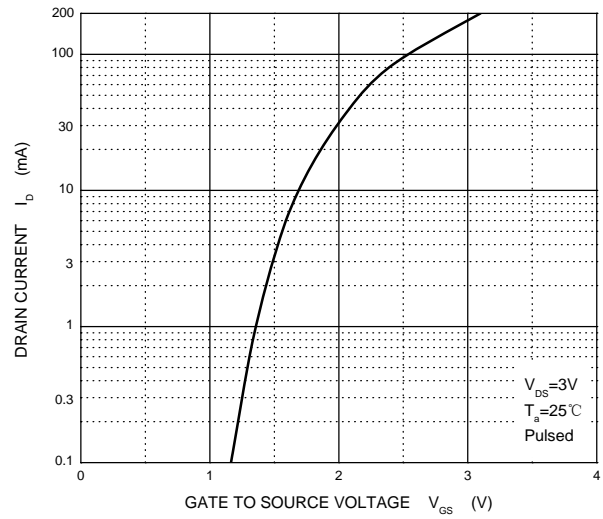


Typical Characteristics

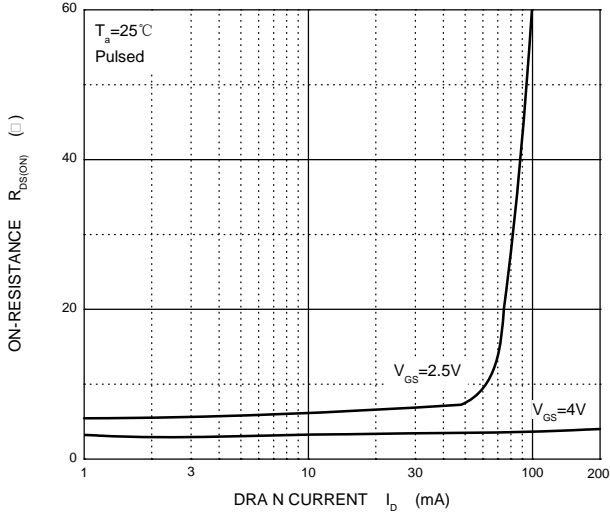
Output Characteristics



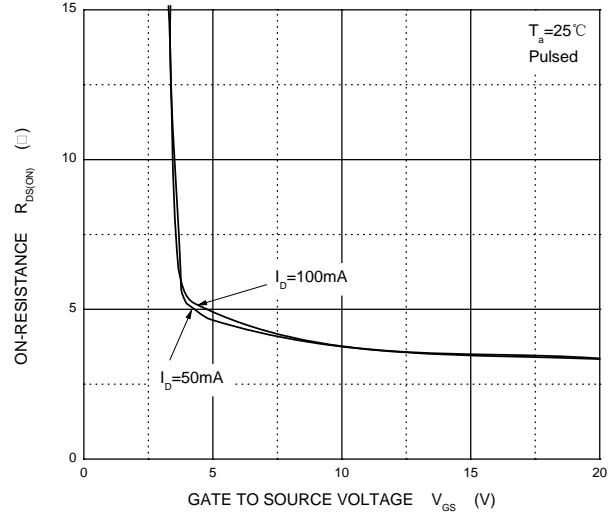
Transfer Characteristics



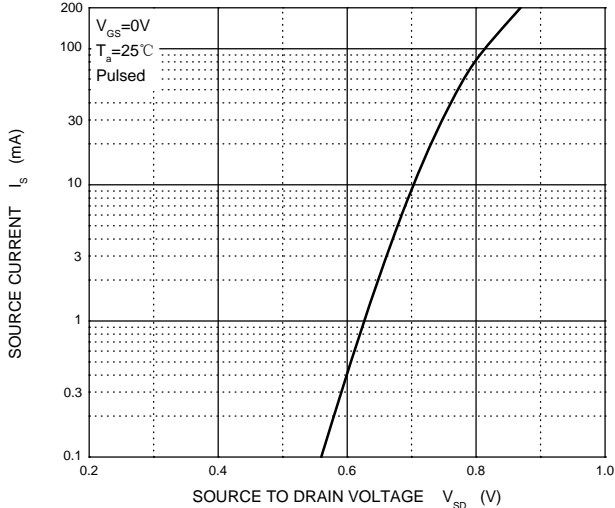
$R_{DS(ON)}$ — I_D



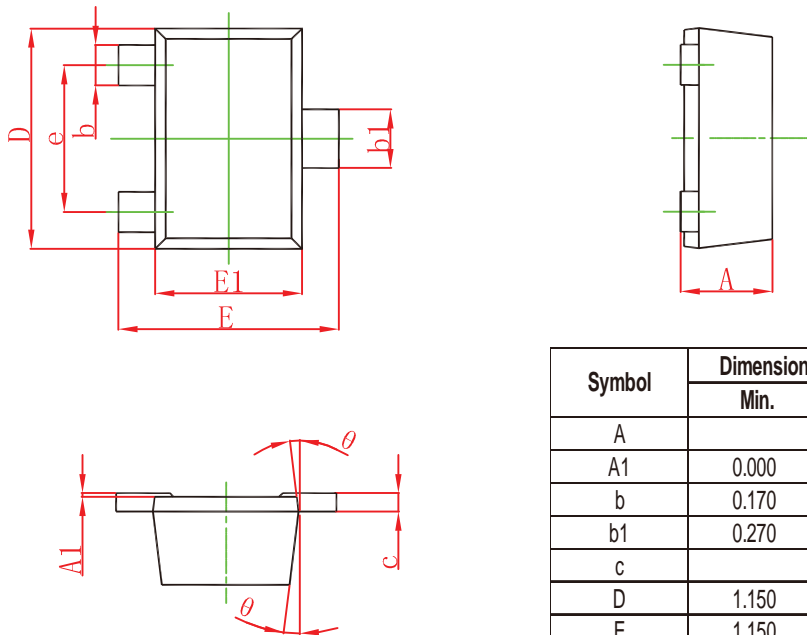
$R_{DS(ON)}$ — V_{GS}



I_S — V_{SD}

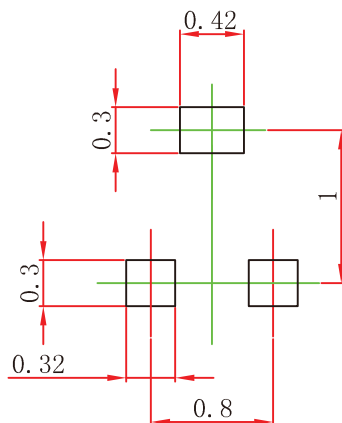


SOT-723 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A		0.500		0.020
A1	0.000	0.050	0.000	0.002
b	0.170	0.270	0.007	0.011
b1	0.270	0.370	0.011	0.015
c		0.150		0.006
D	1.150	1.250	0.045	0.049
E	1.150	1.250	0.045	0.049
E1	0.750	0.850	0.030	0.033
e	0.800TYP.		0.031TYP.	
θ	7° REF.		7° REF.	

SOT-723 Suggested Pad Layout



Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05 mm.
 3. The pad layout is for reference purposes only.